May 2015

# FDD86367_F085

## N-Channel PowerTrench® MOSFET

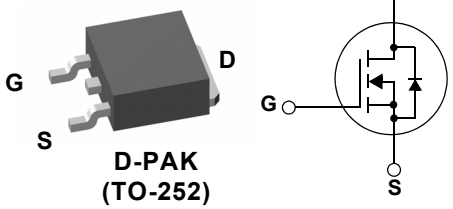
### 80 V, 100 A, 4.2 mΩ

### Features

- Typical $R_{DS(on)}$ = 3.3 mΩ at $V_{GS}$ = 10V, $I_D$ = 80 A
- Typical $Q_{g(tot)}$ = 68 nC at $V_{GS}$ = 10V, $I_D$ = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

### Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems




For current package drawing, please refer to the Fairchild web-site at http://www.fairchildsemi.com/package-drawings/TO/TO252A03.pdf.

### MOSFET Maximum Ratings $T_J$ = 25°C unless otherwise noted.

| Symbol | Parameter | | Ratings | Units |
|---|---|---|---|---|
| $V_{DSS}$ | Drain-to-Source Voltage | | 80 | V |
| $V_{GS}$ | Gate-to-Source Voltage | | ±20 | V |
| $I_D$ | Drain Current - Continuous ($V_{GS}$=10) (Note 1) | $T_C$ = 25°C | 100 | A |
| | Pulsed Drain Current | $T_C$ = 25°C | See Figure 4 | |
| $E_{AS}$ | Single Pulse Avalanche Energy | (Note 2) | 82 | mJ |
| $P_D$ | Power Dissipation | | 227 | W |
| | Derate Above 25°C | | 1.52 | W/°C |
| $T_J$, $T_{STG}$ | Operating and Storage Temperature | | -55 to + 175 | °C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | | 0.66 | °C/W |
| $R_{\theta JA}$ | Maximum Thermal Resistance, Junction to Ambient | (Note 3) | 52 | °C/W |

**Notes:**
1: Current is limited by bondwire configuration.
2: Starting $T_J$ = 25°C, L = 40μH, $I_{AS}$ = 64A, $V_{DD}$ = 80V during inductor charging and $V_{DD}$ = 0V during time in avalanche.
3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$is determined by the board design. The maximum rating presented here is based on mounting on a 1 $in^2$ pad of 2oz copper.

### Package Marking and Ordering Information

| Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|---|---|---|---|---|---|
| FDD86367 | FDD86367_F085 | D-PAK(TO-252) | 13” | 16mm | 2500units |

## Electrical Characteristics $T_J$ = 25°C unless otherwise noted.

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
|---|---|---|---|---|---|---|
| **Off Characteristics** | | | | | | |
| $B_{VDSS}$ | Drain-to-Source Breakdown Voltage | $I_D$ = 250μA, $V_{GS}$ = 0V | 80 | - | - | V |
| $I_{DSS}$ | Drain-to-Source Leakage Current | $V_{DS}$=80V, $V_{GS}$ = 0V, $T_J$ = 25°C | - | - | 1 | μA |
| | | $V_{GS}$ = 0V, $T_J$ = 175°C (Note 4) | - | - | 1 | mA |
| $I_{GSS}$ | Gate-to-Source Leakage Current | $V_{GS}$ = ±20V | - | - | ±100 | nA |
| **On Characteristics** | | | | | | |
| $V_{GS(th)}$ | Gate to Source Threshold Voltage | $V_{GS}$ = $V_{DS}$, $I_D$ = 250μA | 2 | 3 | 4 | V |
| $R_{DS(on)}$ | Drain to Source On Resistance | $I_D$ = 80A, $V_{GS}$= 10V, $T_J$ = 25°C | - | 3.3 | 4.2 | mΩ |
| | | $I_D$ = 80A, $V_{GS}$= 10V, $T_J$ = 175°C (Note 4) | - | 6.6 | 8.4 | mΩ |
| **Dynamic Characteristics** | | | | | | |
| $C_{iss}$ | Input Capacitance | $V_{DS}$ = 40V, $V_{GS}$ = 0V, f = 1MHz | - | 4840 | - | pF |
| $C_{oss}$ | Output Capacitance | | - | 814 | - | pF |
| $C_{rss}$ | Reverse Transfer Capacitance | | - | 31 | - | pF |
| $R_g$ | Gate Resistance | $V_{GS}$ = 0.5V, f = 1MHz | - | 2.3 | - | Ω |
| $Q_{g(ToT)}$ | Total Gate Charge | $V_{GS}$ = 0 to 10V, $V_{DD}$ = 40V, $I_D$ = 80A | - | 68 | 88 | nC |
| $Q_{g(th)}$ | Threshold Gate Charge | $V_{GS}$ = 0 to 2V, $V_{DD}$ = 40V, $I_D$ = 80A | - | 8.8 | - | nC |
| $Q_{gs}$ | Gate-to-Source Gate Charge | $V_{DD}$ = 40V, $I_D$ = 80A | - | 22 | - | nC |
| $Q_{gd}$ | Gate-to-Drain “Miller“ Charge | $V_{DD}$ = 40V, $I_D$ = 80A | - | 14 | - | nC |
| **Switching Characteristics** | | | | | | |
| $t_{on}$ | Turn-On Time | $V_{DD}$ = 40V, $I_D$ = 80A, $V_{GS}$ = 10V, $R_{GEN}$ = 6Ω | - | - | 104 | ns |
| $t_{d(on)}$ | Turn-On Delay | | - | 20 | - | ns |
| $t_r$ | Rise Time | | - | 49 | - | ns |
| $t_{d(off)}$ | Turn-Off Delay | | - | 36 | - | ns |
| $t_f$ | Fall Time | | - | 16 | - | ns |
| $t_{off}$ | Turn-Off Time | | - | - | 80 | ns |
| **Drain-Source Diode Characteristics** | | | | | | |
| $V_{SD}$ | Source-to-Drain Diode Voltage | $I_{SD}$ = 80A, $V_{GS}$ = 0V | - | - | 1.3 | V |
| | | $I_{SD}$ = 40A, $V_{GS}$ = 0V | - | - | 1.2 | V |
| $t_{rr}$ | Reverse-Recovery Time | $V_{DD}$ = 64V, $I_F$ = 80A, $dI_{SD}/dt$ = 100A/μs | - | 68 | 102 | ns |
| $Q_{rr}$ | Reverse-Recovery Charge | | - | 66 | 106 | nC |

**Note:**

4: The maximum value is specified by design at $T_J$ = 175°C. Product is not tested to this condition in production.

## Typical Characteristics

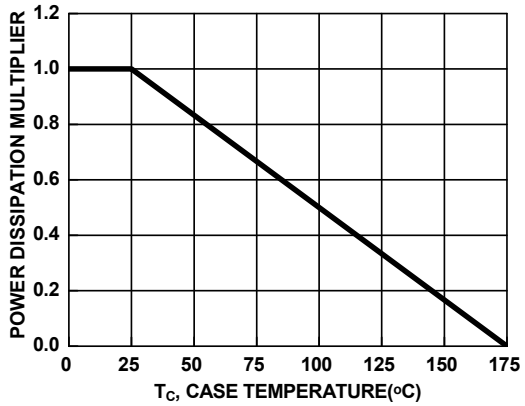



**Figure 1. Normalized Power Dissipation vs. Case Temperature**

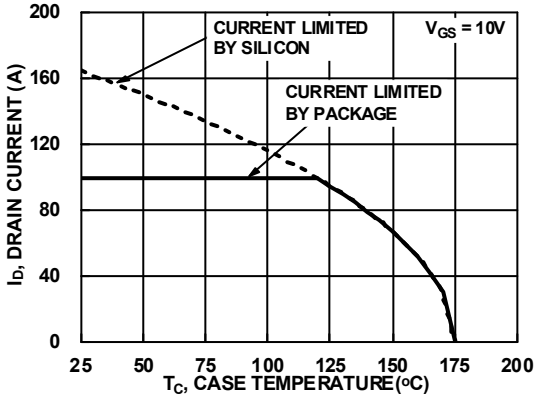



**Figure 2. Maximum Continuous Drain Current vs. Case Temperature**

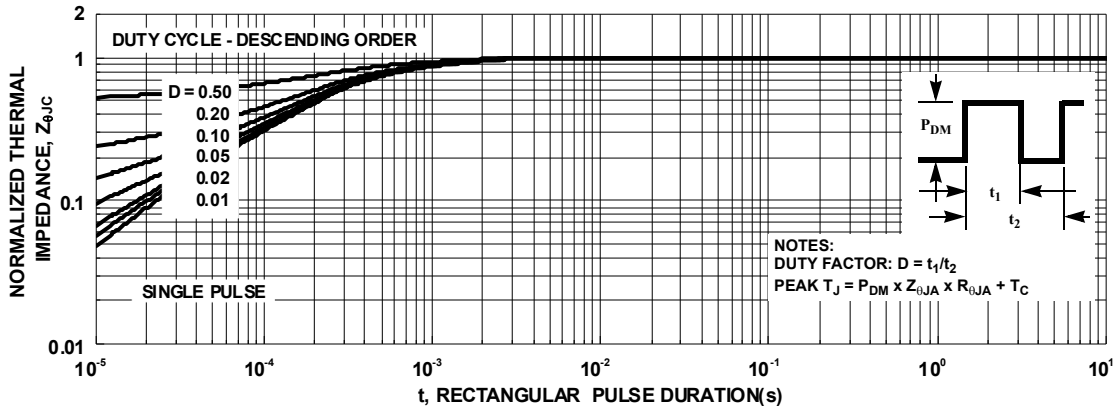



**Figure 3. Normalized Maximum Transient Thermal Impedance**

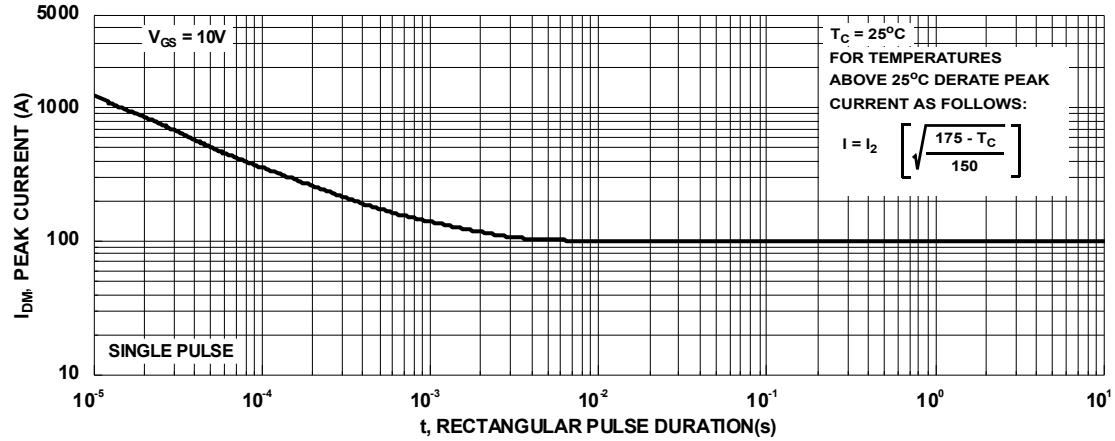



**Figure 4. Peak Current Capability**

## Typical Characteristics

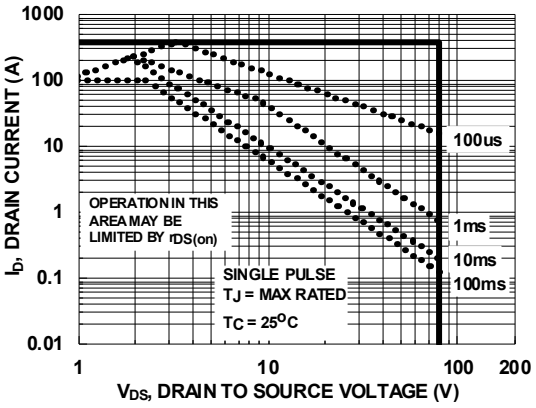
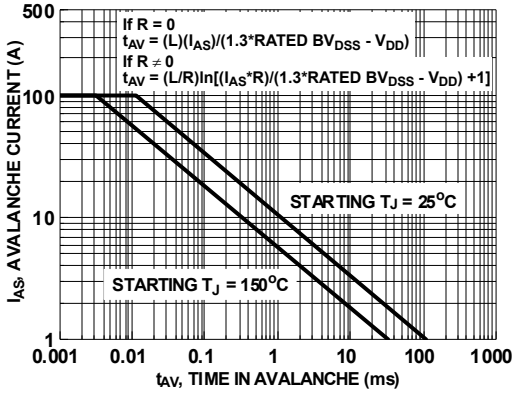



**Figure 5. Forward Bias Safe Operating Area**




NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

**Figure 6. Unclamped Inductive Switching Capability**

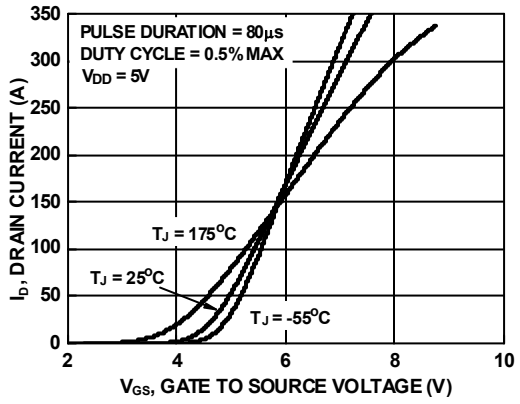



**Figure 7. Transfer Characteristics**

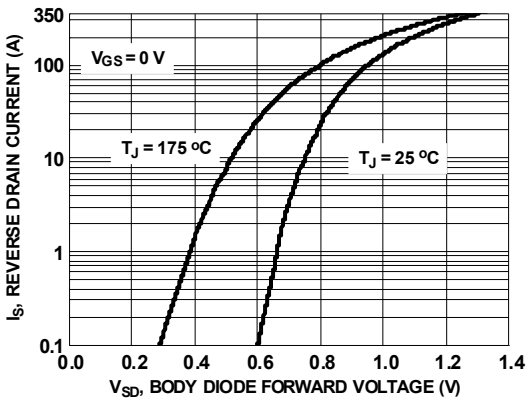



**Figure 8. Forward Diode Characteristics**

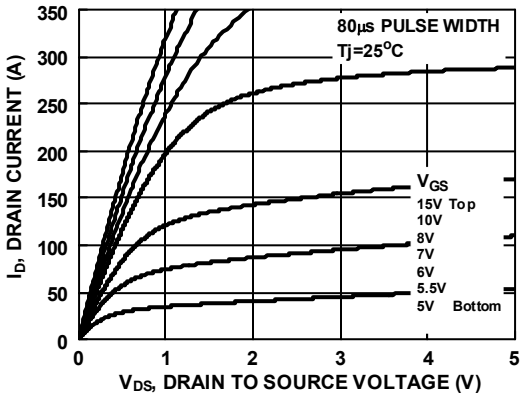



**Figure 9. Saturation Characteristics**

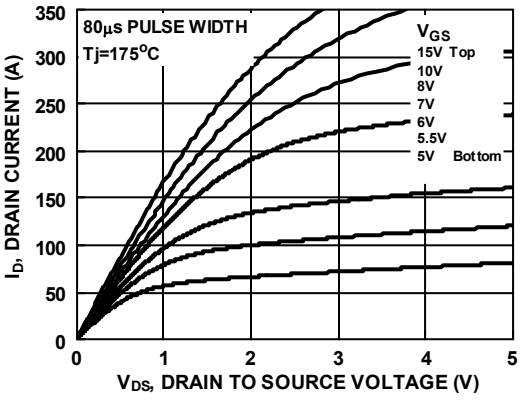



**Figure 10. Saturation Characteristics**

## Typical Characteristics

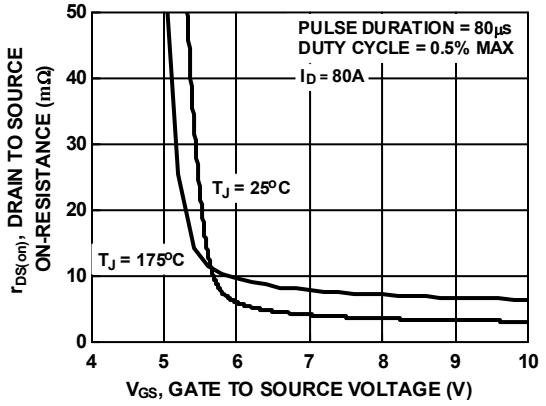



**Figure 11. $R_{DSON}$ vs. Gate Voltage**

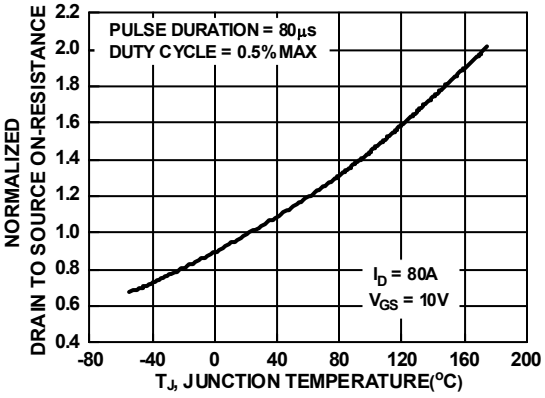



**Figure 12. Normalized $R_{DSON}$ vs. Junction Temperature**

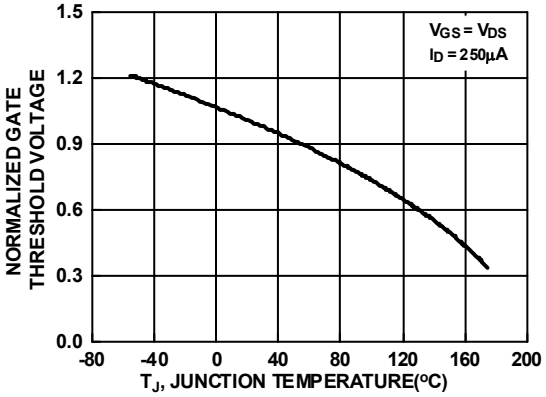



**Figure 13. Normalized Gate Threshold Voltage vs. Temperature**

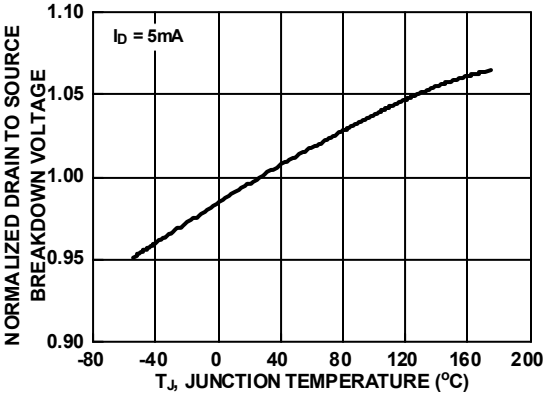



**Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature**

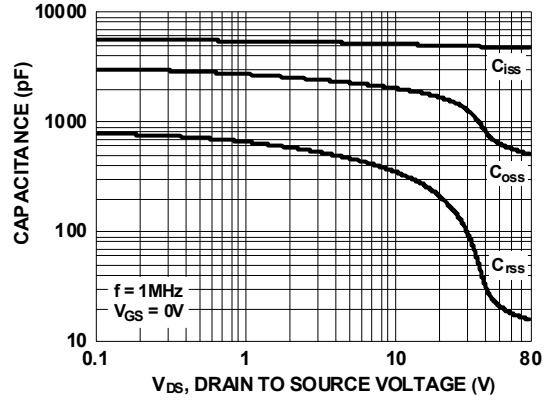



**Figure 15. Capacitance vs. Drain to Source Voltage**

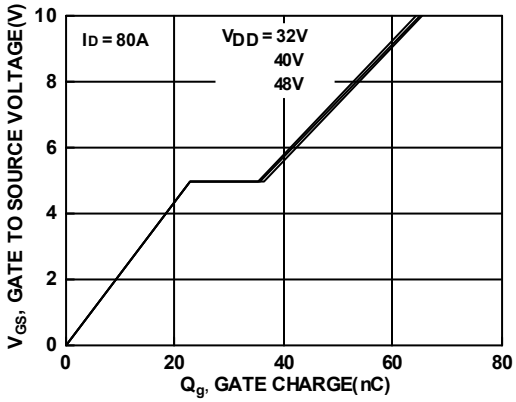



**Figure 16. Gate Charge vs. Gate to Source Voltage**

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